

# DATA SHEET



## **BGD714**

**750 MHz, 20.3 dB gain power  
doubler amplifier**

Product specification  
Supersedes data of 2001 Oct 29

2001 Nov 02

## 750 MHz, 20.3 dB gain power doubler amplifier

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## FEATURES

- Excellent linearity
- Extremely low noise
- Excellent return loss properties
- Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

## APPLICATIONS

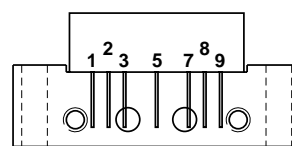
- CATV systems operating in the 40 to 750 MHz frequency range.

## DESCRIPTION

Hybrid amplifier module in a SOT115J package operating with a voltage supply of 24 V (DC).

## PINNING - SOT115J

PIN	DESCRIPTION
1	input
2, 3	common
5	+V <sub>B</sub>
7, 8	common
9	output



Side view

MSA319

Fig.1 Simplified outline.

## QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 45 MHz	20	20.6	dB
		f = 750 MHz	20.8	21.8	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	380	410	mA

## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>B</sub>	supply voltage	–	30	V
V <sub>i</sub>	RF input voltage	–	70	dBmV
T <sub>stg</sub>	storage temperature	–40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	–20	+100	°C

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**CHARACTERISTICS**Bandwidth 40 to 750 MHz;  $V_B = 24$  V;  $T_{mb} = 35$  °C;  $Z_S = Z_L = 75 \Omega$ 

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 45 MHz	20	20.3	20.6	dB
		f = 750 MHz	20.8	21.3	21.8	dB
SL	slope straight line	f = 45 to 100 MHz; note 1	0.5	1	1.5	dB
FL	flatness straight line	f = 45 to 100 MHz	–	–	±0.35	dB
		f = 100 to 700 MHz	–	–	±0.5	dB
		f = 700 to 750 MHz	–	–	±0.15	dB
S <sub>11</sub>	input return losses	f = 45 to 80 MHz	23	–	–	dB
		f = 80 to 160 MHz	23	–	–	dB
		f = 160 to 320 MHz	21	–	–	dB
		f = 320 to 550 MHz	20	–	–	dB
		f = 550 to 650 MHz	20	–	–	dB
		f = 650 to 750 MHz	19	–	–	dB
		f = 750 to 790 MHz	17	–	–	dB
S <sub>22</sub>	output return losses	f = 45 to 80 MHz	23	–	–	dB
		f = 80 to 160 MHz	23	–	–	dB
		f = 160 to 320 MHz	20	–	–	dB
		f = 320 to 550 MHz	20	–	–	dB
		f = 550 to 650 MHz	20	–	–	dB
		f = 650 to 750 MHz	19	–	–	dB
		f = 750 to 790 MHz	17	–	–	dB
S <sub>21</sub>	phase response	f = 50 MHz	–45	–	+45	deg
CTB	composite triple beat	112 channels flat; V <sub>o</sub> = 44 dBmV; f <sub>m</sub> = 745.25 MHz	–	–	–61	dB
		79 channels; V <sub>o</sub> = 44 dBmV; f <sub>m</sub> = 547.25 MHz	–	–	–67	dB
		79 channels; f <sub>m</sub> = 445.25 MHz; V <sub>o</sub> = 49.3 dBmV at 547 MHz; note 2	–	–	–62	dB
X <sub>mod</sub>	cross modulation	112 channels flat; V <sub>o</sub> = 44 dBmV; f <sub>m</sub> = 55.25 MHz	–	–	–62	dB
		79 channels flat; V <sub>o</sub> = 44 dBmV; f <sub>m</sub> = 55.25 MHz	–	–	–66	dB
		79 channels; f <sub>m</sub> = 745.25 MHz; V <sub>o</sub> = 49.3 dBmV at 547 MHz; note 2	–	–	–58	dB

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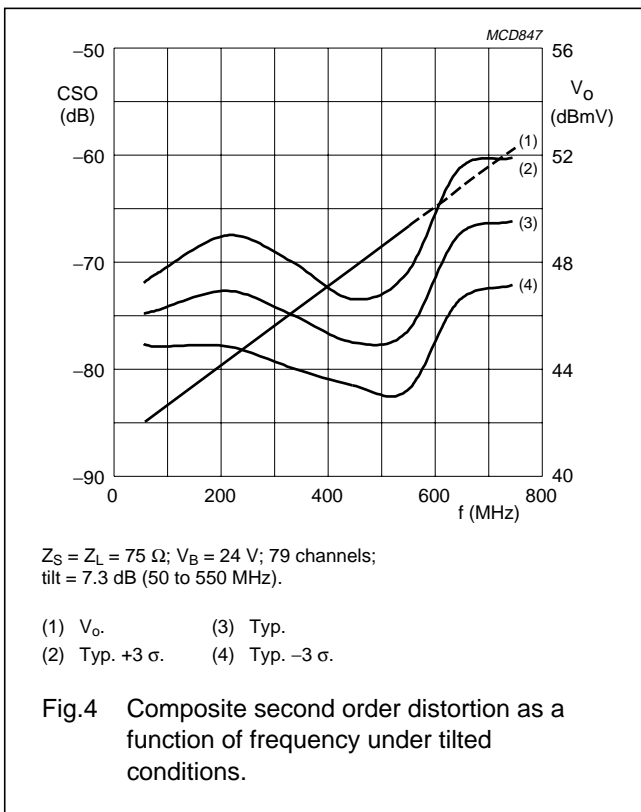
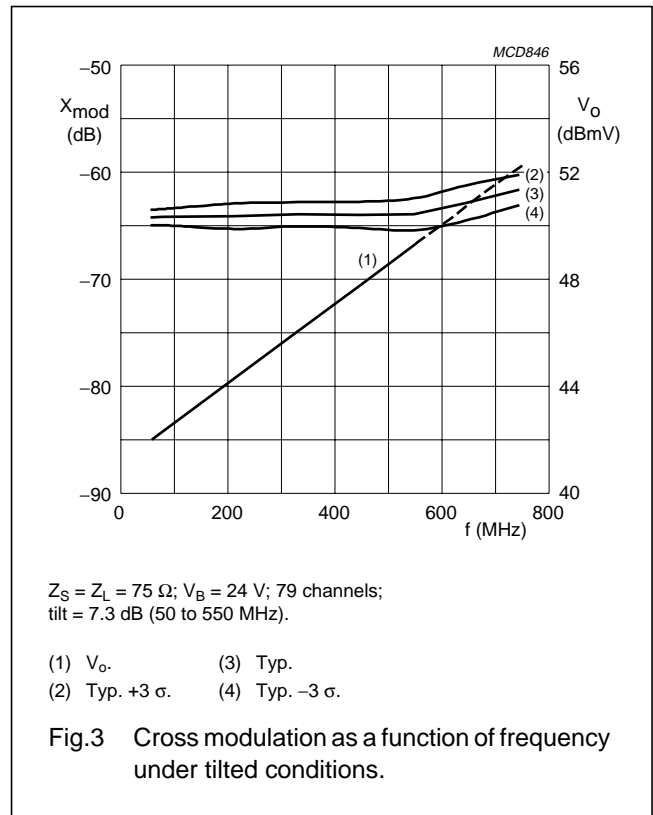
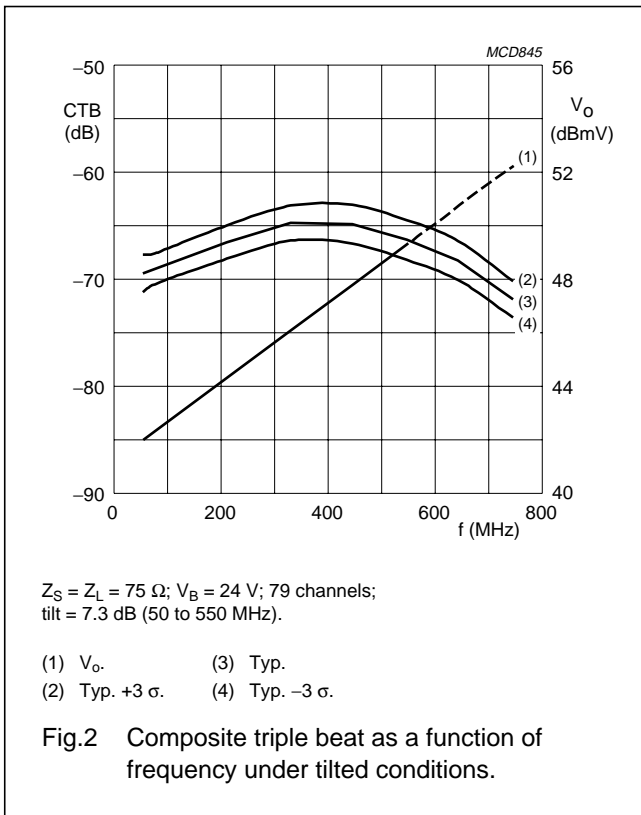
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
CSO	composite second order distortion	112 channels flat; $V_o = 44$ dBmV; $f_m = 746.5$ MHz	–	–	–62	dB
		79 channels flat; $V_o = 44$ dBmV; $f_m = 548.5$ MHz	–	–	–67	dB
		79 channels; $f_m = 746.5$ MHz; $V_o = 49.3$ dBmV at 547 MHz; note 2	–	–	–60	dB
$d_2$	second order distortion	note 3	–	–	–74	dB
$V_o$	output voltage	$d_{im} = -60$ dB; note 4	64	–	–	dBmV
NF	noise figure	$f = 50$ MHz	–	–	5.5	dB
		$f = 550$ MHz	–	–	5.5	dB
		$f = 750$ MHz	–	–	7	dB
$I_{tot}$	total current consumption (DC)	note 5	380	395	410	mA

**Notes**

- Slope straight line is defined as gain at 750 MHz – gain at 45 MHz.
- Tilt = 7.3 dB (55 to 547 MHz).
- $f_p = 55.25$  MHz;  $V_p = 44$  dBmV;  
 $f_q = 691.25$  MHz;  $V_q = 44$  dBmV;  
measured at  $f_p + f_q = 746.5$  MHz.
- Measured according to DIN45004B:  
 $f_p = 740.25$  MHz;  $V_p = V_o$ ;  
 $f_q = 747.25$  MHz;  $V_q = V_o - 6$  dB;  
 $f_r = 749.25$  MHz;  $V_r = V_o - 6$  dB;  
measured at  $f_p + f_q - f_r = 738.25$  MHz.
- The module normally operates at  $V_B = 24$  V, but is able to withstand supply transients up to 30 V.

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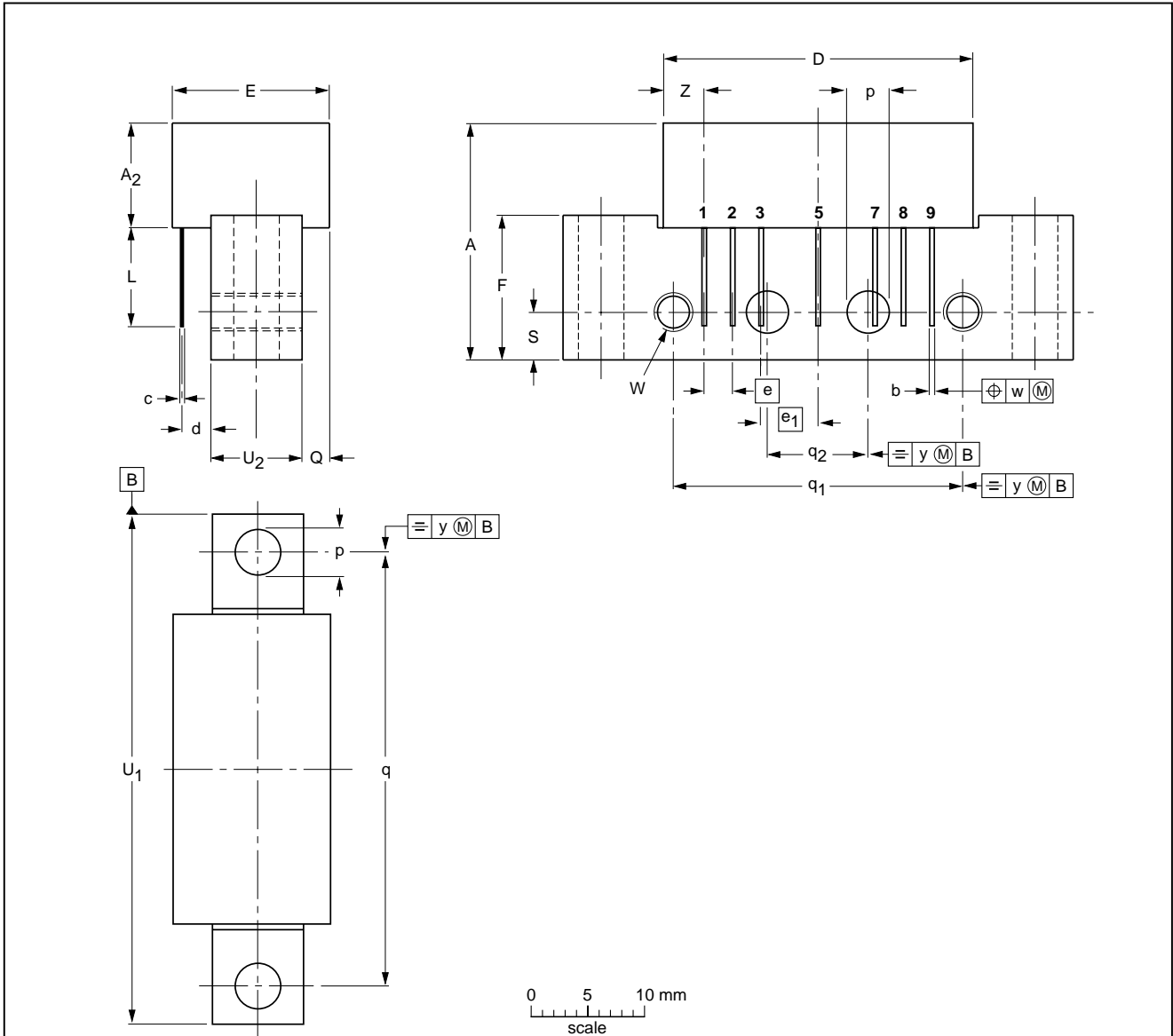
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PACKAGE OUTLINE

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads

SOT115J



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A <sub>2</sub> max.	b	c	D max.	d max.	E max.	e	e <sub>1</sub>	F	L min.	p	Q max.	q	q <sub>1</sub>	q <sub>2</sub>	S	U <sub>1</sub> max.	U <sub>2</sub>	W	w	y	Z max.
mm	20.8	9.1	0.51 0.38	0.25	27.2	2.54	13.75	2.54	5.08	12.7	8.8	4.15 3.85	2.4	38.1	25.4	10.2	4.2	44.75	8	6-32 UNC	0.25	0.1	3.8

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT115J						99-02-06

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